

isc N-Channel MOSFET Transistor

IRFB4229, IIRFB4229

• FEATURES

- Static drain-source on-resistance:
 R_{DS}(on) ≤46mΩ
- Enhancement mode
- · Fast Switching Speed
- · 100% avalanche tested
- Minimum Lot-to-Lot variations for robust device performance and reliable operation

DESCRITION

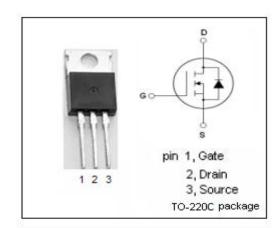
• 175℃ operating junction temperature and high repetitive peak current capability

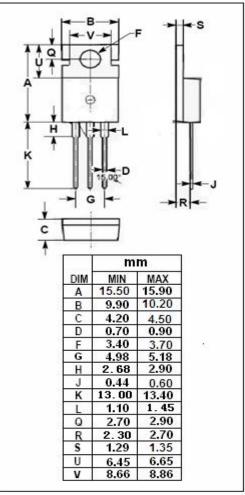
• ABSOLUTE MAXIMUM RATINGS(Ta=25°C)

| SYMBOL | PARAMETER | VALUE | UNIT | |
|------------------|--|---------|------------|--|
| V _{DSS} | Drain-Source Voltage | 250 | V | |
| V _{GS} | Gate-Source Voltage | ±30 | V | |
| I _D | Drain Current-Continuous | 46 | А | |
| I _{DM} | Drain Current-Single Pulsed | 180 | А | |
| P_D | Total Dissipation @Tc=25°C | 330 | W | |
| Tj | Max. Operating Junction Temperature 17 | | $^{\circ}$ | |
| T _{stg} | Storage Temperature | -40~175 | $^{\circ}$ | |

• THERMAL CHARACTERISTICS

| SYMBOL | PARAMETER | MAX | UNIT |
|-----------|---|------|------|
| Rth(ch-c) | Channel-to-case thermal resistance | 0.45 | °C/W |
| Rth(ch-a) | Rth(ch-a) Channel-to-ambient thermal resistance | | °C/W |







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ELECTRICAL CHARACTERISTICS

T_C=25°C unless otherwise specified

| SYMBOL | PARAMETER | CONDITIONS | MIN | ТҮР | MAX | UNIT |
|---------------------|--------------------------------|--|-----|-----|------|------|
| BV _{DSS} | Drain-Source Breakdown Voltage | V _{GS} =0V; I _D =250 μ A | 250 | | | V |
| V _{GS(th)} | Gate Threshold Voltage | V _{DS} =V _{GS} ; I _D =250 μ A | 3 | | 5 | V |
| R _{DS(on)} | Drain-Source On-Resistance | V _{GS} =10V; I _D =26A | | | 46 | mΩ |
| I _{GSS} | Gate-Source Leakage Current | V _{GS} = ±20V | | | ±0.1 | μА |
| I _{DSS} | Drain-Source Leakage Current | V _{DS} =250V; V _{GS} = 0V | | | 20 | μА |
| V _{SD} | Diode forward voltage | Is=26A; V _{GS} = 0V | | | 1.3 | V |

NOTICE:

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